

650V SiC Schottky Diode

FEATURES

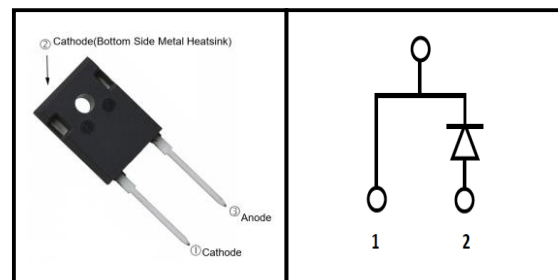
- Low Conduction and Switch Loss
- Positive Temperature Coefficient on VF
- Temperature Independent Switching Behavior
- Fast Reverse Recovery
- High Surge Current Capability
- Pb-free lead plating

BENEFITS

- Higher System Efficiency
- Parallel Device Convenience
- High Temperature Application
- High Frequency Operation
- Hard Switching & High Reliability
- Environmental Protection

APPLICATIONS

- Switch Mode Power Supply (SMPS)
- Uninterruptible Power Supply (UPS)
- Power Factor Correction (PFC)
- Solar/ Wind Renewable Energy
- Power Inverters
- Motor Drives



Device Marking and Package Information

Device	Package	Marking
C2S065F030B	TO-247-2L	C2S065F030B

Absolute Maximum Ratings $T_C = 25^\circ\text{C}$, unless otherwise noted

Parameter	Symbol	Test Conditions	Value	Unit
Peak Repetitive Reverse Voltage	V_{RRM}	$T_J = 25^\circ\text{C}$	650	V
Peak Reverse Surge Voltage	V_{RSM}	$T_J = 25^\circ\text{C}$	650	V
DC Blocking Voltage	V_R	$T_J = 25^\circ\text{C}$	650	V
Continuous Forward Current	I_F	$T_J \leq 135^\circ\text{C}$	30	A
Repetitive Peak Forward Surge Current	I_{FRM}	$T_C = 25^\circ\text{C}$, $T_P = 8.3\text{ms}$ Half Sine Wave	150	A
Maximum Case Temperature	T_C		135	$^\circ\text{C}$
Operating Junction and Storage Temperature	T_J , T_{stg}		-55~175	$^\circ\text{C}$

Thermal Resistance

Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case	R_{thJC}	0.65	$^\circ\text{C/W}$

Specifications $T_J = 25^{\circ}\text{C}$, unless otherwise noted

Parameter	Symbol	Test Conditions	Value		Unit
			Typ.	Max.	
Forward Voltage	V_F	$I_F = 30\text{A}, T_J = 25^{\circ}\text{C}$	1.5	1.65	V
		$I_F = 30\text{A}, T_J = 175^{\circ}\text{C}$	1.77	2.3	V
Reverse Current	I_R	$V_R = 650\text{V}, T_J = 25^{\circ}\text{C}$	1.5	20	μA
		$V_R = 650\text{V}, T_J = 175^{\circ}\text{C}$	15	100	μA
Total Capacitive Charge	Q_C	$I_F = 30\text{A}, di/dt = 200\text{A}/\mu\text{s}$ $V_R = 650\text{V}, T_J = 25^{\circ}\text{C}$	67	--	nC
Total Capacitance	C	$V_R = 0\text{V}, T_J = 25^{\circ}\text{C}, f = 1\text{ MHz}$	1800	--	pF
		$V_R = 200\text{V}, T_J = 25^{\circ}\text{C}, f = 1\text{ MHz}$	176	--	
		$V_R = 400\text{V}, T_J = 25^{\circ}\text{C}, f = 1\text{ MHz}$	144	--	

Typical Characteristics $T_J = 25^\circ\text{C}$, unless otherwise noted

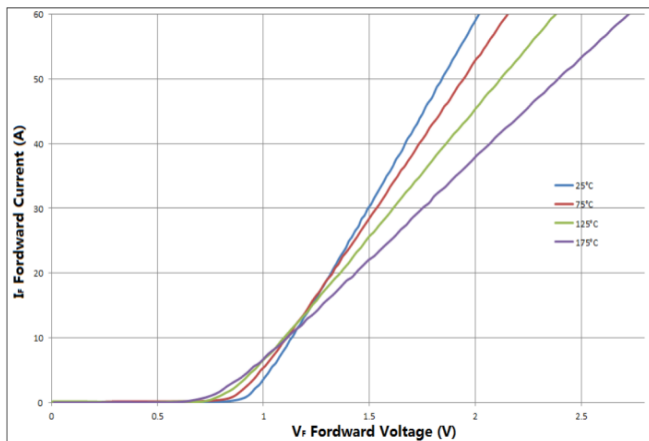


Fig. 1 Forward Characteristics

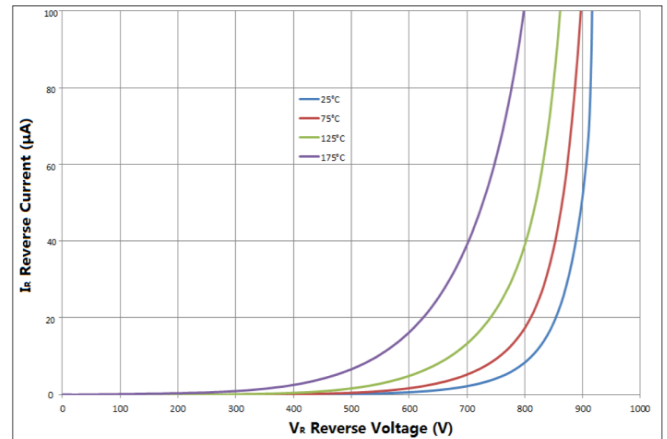


Fig. 2 Reverse Characteristics

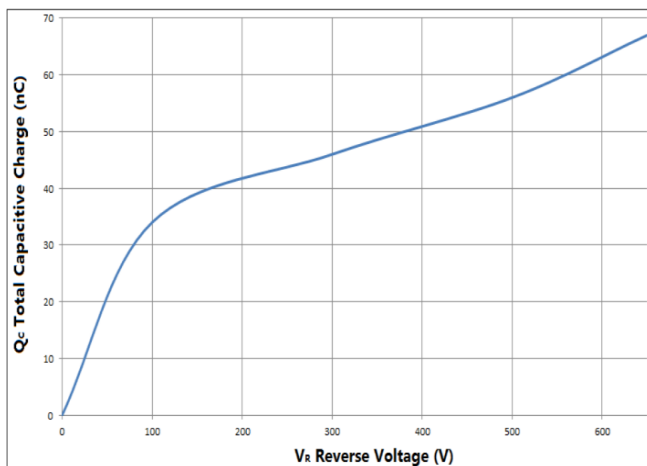


Fig. 3 Total Capacitance Charges.
Reverse Voltage

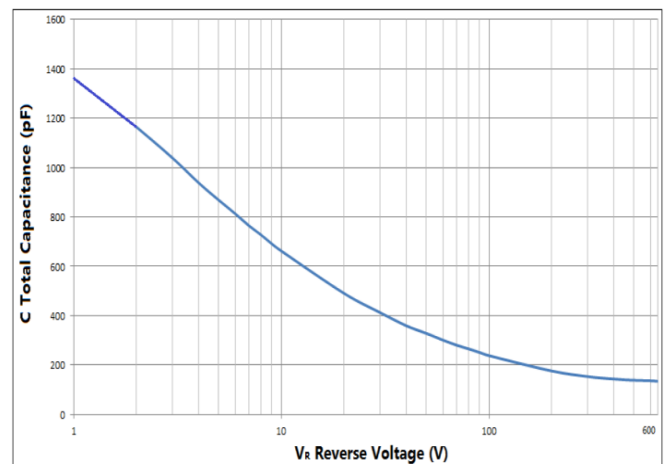


Fig. 4 Total Capacitance vs. Reverse Voltage

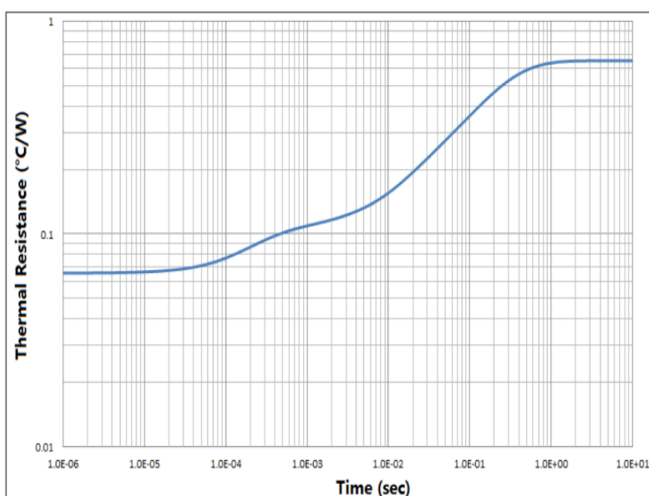
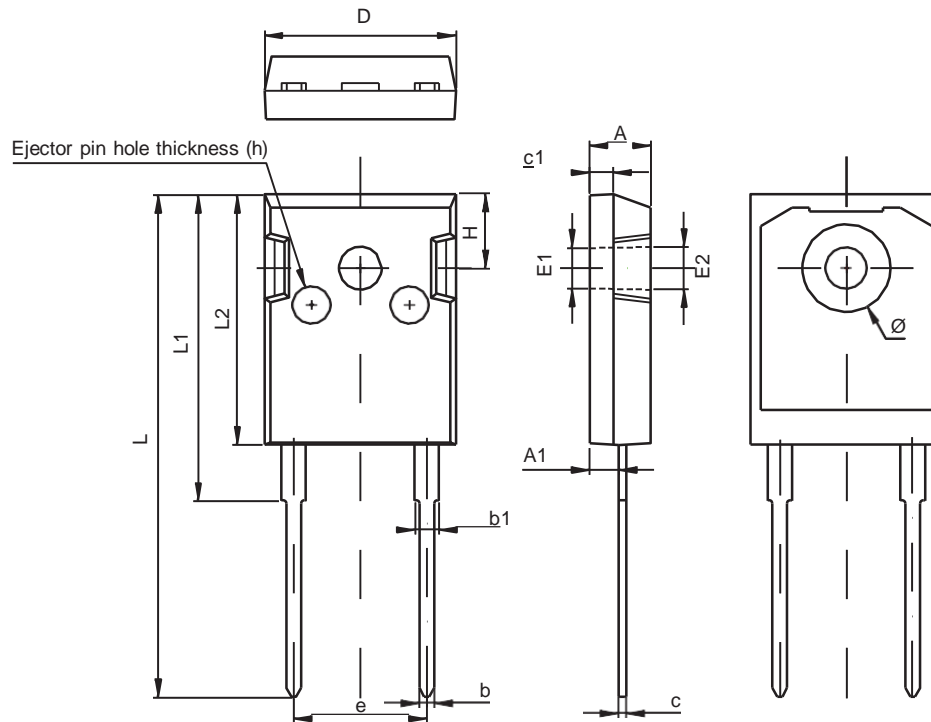


Fig. 5 Transient Thermal Impedance

TO-247-2



TO-247-2L DIMENSIONS

SYMBOL	DIMENSIONS IN MILLIMETERS		DIMENSIONS IN INCHES	
	MIN.	MAX.	MIN.	MAX.
A	4.850	5.150	0.191	0.200
A1	2.200	2.600	0.087	0.102
b	1.000	1.400	0.039	0.055
b1	1.800	2.200	0.071	0.087
c	0.500	0.700	0.020	0.028
c1	1.900	2.100	0.075	0.083
D	15.450	15.750	0.608	0.620
E1	3.500 Ref.		0.138 Ref.	
E2	3.600 Ref.		0.142 Ref.	
L	40.900	41.300	1.610	1.626
L1	24.800	25.100	0.976	0.988
L2	20.300	20.600	0.799	0.811
Ø	7.100	7.300	0.280	0.287
e	10.900 Typ.		0.429 Typ.	
H	5.980 Typ.		0.235 Typ.	
h	0.000	0.300	0.000	0.012

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